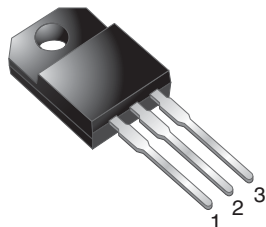
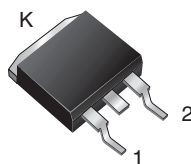
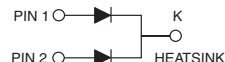


Dual Common Cathode Schottky Rectifier

ITO-220AB

MBRF15xxCT

D²PAK (TO-263AB)

MBRB15xxCT

RoHS
COMPLIANT

FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB)) package
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESIGN SUPPORT TOOLS


[click logo to get started](#)

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: ITO-220AB, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified
("X" denotes revision code, e.g. A, B,...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 7.5 A
V_{RRM}	45 V, 60 V
I_{FSM}	150 A
V_F	0.57 V, 0.65 V
$T_J \text{ max.}$	150 °C
Package	ITO-220AB, D ² PAK (TO-263AB)
Circuit configuration	Common cathode

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRB1545CT	MBRB1560CT	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	45	60	V	
Working peak reverse voltage	V _{RWM}	45	60		
Maximum DC blocking voltage	V _{DC}	45	60		
Maximum average forward rectified current at T _C = 105 °C	total device	15		A	
	per diode	7.5			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150			
Peak repetitive reverse surge current per diode at t _p = 2.0 μs, 1 kHz	I _{RRM}	1.0	0.5		
Voltage rate of change (rated V _R)	dV/dt	10 000			V/μs
Operating junction temperature range	T _J	-65 to +150			°C
Storage temperature range	T _{STG}	-65 to +175			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500		V	



ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB1545CT	MBRB1560CT	UNIT
Maximum instantaneous forward voltage per diode	$V_F^{(1)}$	$I_F = 7.5\text{ A}$	$T_C = 25\text{ }^{\circ}\text{C}$	-	0.75	V
		$I_F = 7.5\text{ A}$	$T_C = 125\text{ }^{\circ}\text{C}$	0.57	0.65	
		$I_F = 15\text{ A}$	$T_C = 25\text{ }^{\circ}\text{C}$	0.84	-	
		$I_F = 15\text{ A}$	$T_C = 125\text{ }^{\circ}\text{C}$	0.72	-	
Maximum instantaneous reverse current at DC blocking voltage per diode	$I_R^{(2)}$	Rated V_R	$T_C = 25\text{ }^{\circ}\text{C}$	0.1	1.0	mA
			$T_C = 125\text{ }^{\circ}\text{C}$	15	50	

Notes(1) Pulse test: 300 μs pulse width, 1 % duty cycle(2) Pulse test: pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)				
PARAMETER	SYMBOL	MBRF	MBRB	UNIT
Maximum thermal resistance per diode	$R_{\theta JA}$	-	60	$^{\circ}\text{C/W}$
	$R_{\theta JC}$	5.0	3.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	MBRF1545CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB1545CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB1545CT-E3/81	1.35	81	800/reel	Tape and reel
ITO-220AB	MBRF1545CTHE3_A/P ⁽¹⁾	1.99	P	50/tube	Tube
TO-263AB	MBRB1545CTHE3_B/P ⁽¹⁾	1.35	P	50/tube	Tube
TO-263AB	MBRB1545CTHE3_B/I ⁽¹⁾	1.35	I	800/reel	Tape and reel

Note

(1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

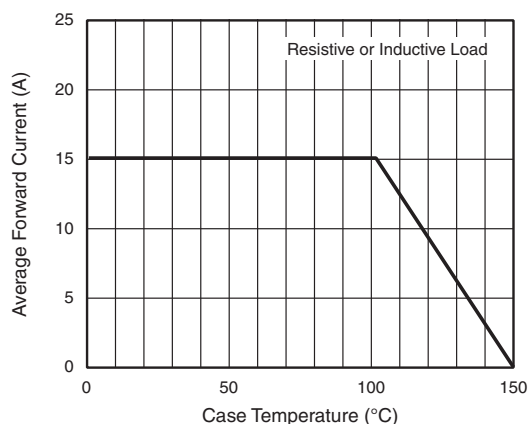


Fig. 1 - Forward Current Derating Curve

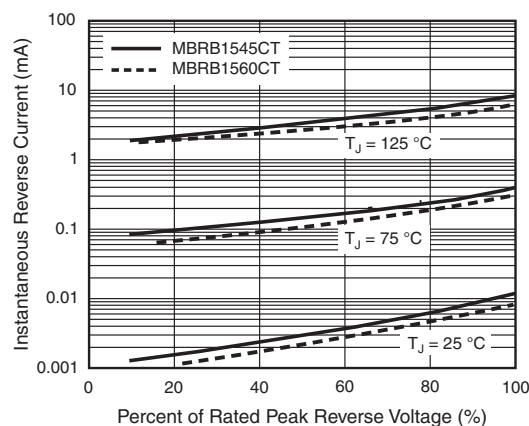


Fig. 4 - Typical Reverse Characteristics Per Diode

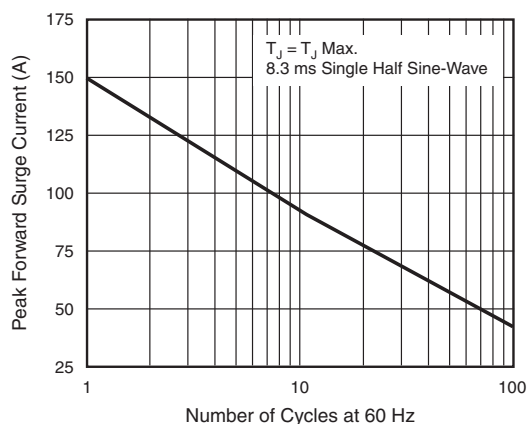


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

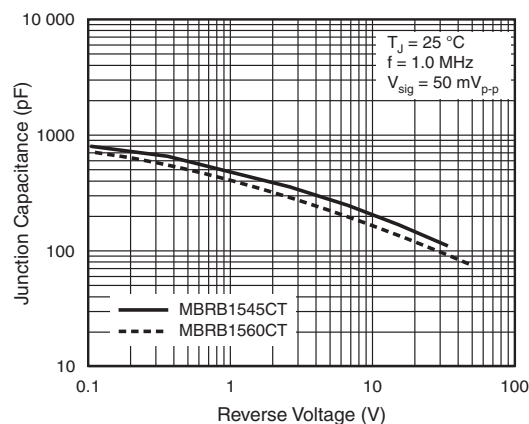


Fig. 5 - Typical Junction Capacitance Per Diode

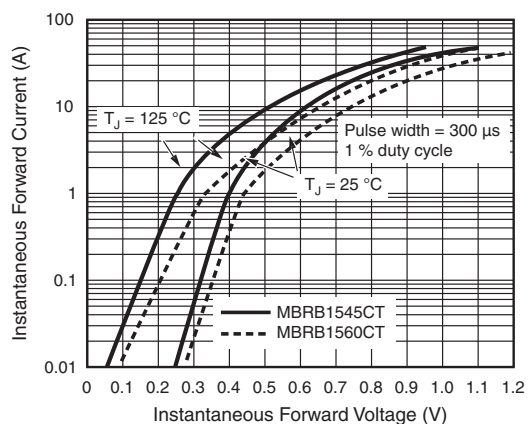


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

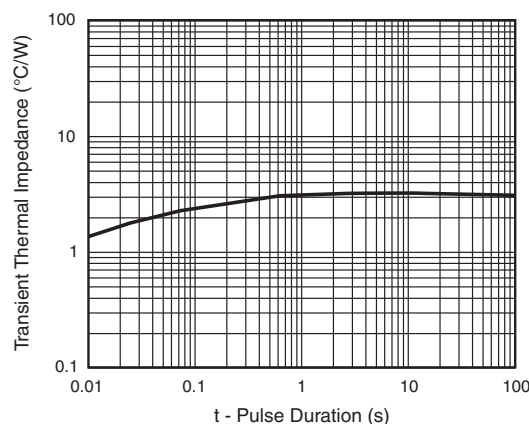
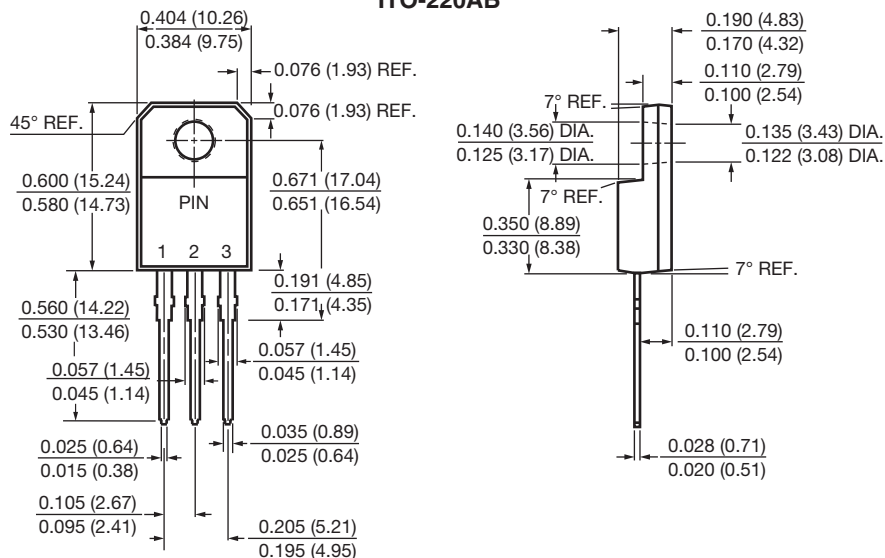


Fig. 6 - Typical Transient Thermal Impedance Per Diode

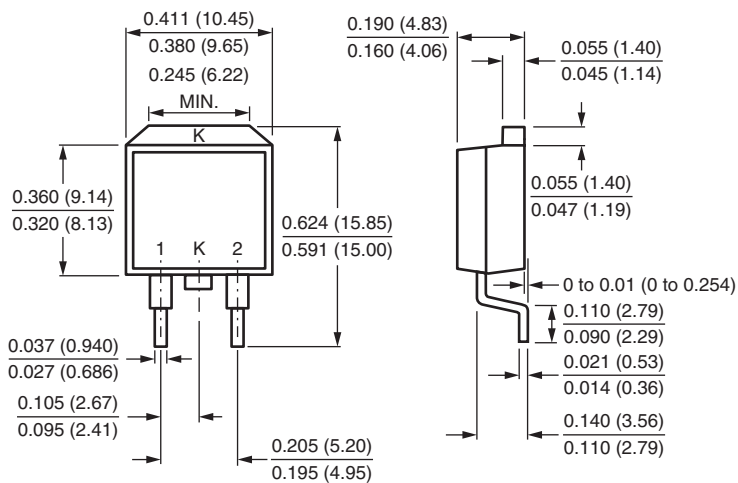


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

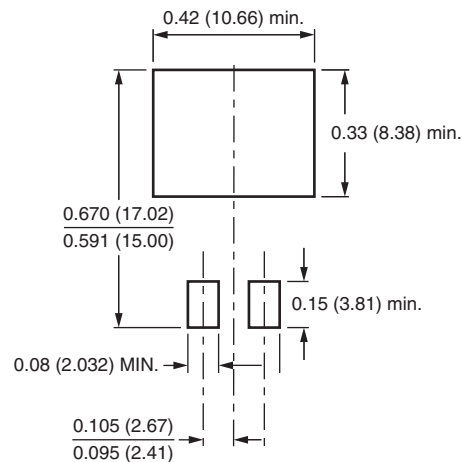
ITO-220AB



D²PAK (TO-263AB)



Mounting Pad Layout





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